

Cyclotron Resonance of Wigner Crystals on Liquid Helium

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The cyclotron resonance of the correlated two-dimensional electrons on liquid helium in high magnetic fields is investigated on the basis of the newly developed theory. Electrons are assumed to form a Wigner crystal, and the electron correlation effect is taken into account through the self-consistently determined Wigner phonons, where the electron-electron interaction, the electron-ripplon and electron-vapor atom scatterings are considered on the same footing. The numerical calculations show a very good agreement with experiments without any fitting parameters.

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I. INTRODUCTION

The cyclotron resonance (CR) is considered to be one of the basic techniques for the investigation of the properties of the 2D electrons, particularly the electrons which form a Wigner crystal^{1,2}. Though there are cumulative theories on the CR of the Wigner crystal on liquid helium^{3,4}, this problem is still controversial as to how the electron Coulomb interaction is taken into account. In this report, we present a new way to incorporate the electron correlation and the electron scattering effects, which was successful to interpret the CR of 2D electrons in the semiconductor heterostructures⁵, and give the theoretical analysis of the CR of the Wigner crystal on the surface of liquid helium in high magnetic fields. The electron-electron interaction, electron-ripplon and electron-vapor atom scattering are taken into account through the Wigner phonon spectra modified by the scatterings. The present systematic method should be compared to the existing phenomenological theories⁴. The dynamic structure factor and the CR linewidth are calculated, and the good agreement is obtained with experiments without any phenomenological parameters.

II. MODEL

We consider that the 2D electrons on the surface of liquid helium form a Wigner crystal (WC) due to the electron Coulomb interaction. Then the Hamiltonian of the system is given by

$$H = \sum_{\mathbf{k}, j=\pm} \hbar \Omega_{\mathbf{k}j}^{(0)} a_{\mathbf{k}j}^{\dagger} a_{\mathbf{k}j} + V_{e-r} + V_{e-v}, \quad (1)$$

where $\Omega_{\mathbf{k}j}^{(0)}$'s are the unperturbed Wigner phonon frequency in a magnetic field, $a_{\mathbf{k}j}^{\dagger}$ and $a_{\mathbf{k}j}$ their creation

and annihilation operators, respectively, j ($j = \pm$) denotes the phonon mode, and V_{e-r} and V_{e-v} are the scattering potentials due to ripples and vapor atoms of ⁴He, respectively.

The ripplon scattering potential is expressed as

$$V_{e-r} = \frac{1}{\sqrt{A}} \sum_{n, \mathbf{q}} eF(q) \sqrt{\frac{\hbar q}{2\rho\nu_q}} e^{i\mathbf{q} \cdot \mathbf{r}_n} (b_{\mathbf{q}} + b_{\mathbf{q}}^{\dagger}), \quad (2)$$

where A is the area of the system, $\nu_q = (\alpha/\rho)^{1/2} q^{3/2}$ the ripplon frequency with α and ρ the surface tension constant and mass density of liquid helium, respectively, $b_{\mathbf{q}}^{\dagger}$ and $b_{\mathbf{q}}$ are the creation and annihilation operators of a ripplon with wave vector $\mathbf{q}$, respectively, $\mathbf{r}_n$ the position vector of the n th electron parallel to the surface, and $F(q)$ the q -dependent effective holding field which takes the form:

$$eF(q) = eE_z + \frac{\hbar^2 q^2}{2ma_0} w\left(\frac{qb}{2}\right). \quad (3)$$

Here E_z is the applied holding electric field perpendicular to the liquid surface, a_0 and b are given by⁶

$$a_0 = \frac{4\hbar^2(\epsilon_{\text{He}} + 1)}{me^2(\epsilon_{\text{He}} - 1)}, \quad (4)$$

$$b = \frac{4a_0}{3\lambda} \sinh\left(\frac{1}{3} \sinh^{-1} \frac{9\lambda}{4}\right), \quad (5)$$

$$\lambda = \sqrt{2ma_0^3 eE_z/\hbar}, \quad (6)$$

where ϵ_{He} is the dielectric constant of liquid helium, and the function $w(x)$ is given by

$$w(x) = \begin{cases} \frac{1}{1-x^2} \left[\frac{1}{\sqrt{1-x^2}} \ln \frac{1+\sqrt{1-x^2}}{x} - 1 \right], & (x < 1), \\ \frac{1}{x^2-1} \left[1 - \frac{1}{\sqrt{x^2-1}} \arctan \sqrt{x^2-1} \right], & (x > 1). \end{cases} \quad (7)$$

The vapor scattering potential V_{e-v} is a contact type

interaction and given by⁶

$$V_{e-v} = V_0 \sum_{a,n} \delta(\mathbf{R}_a - \mathbf{r}_n) \delta(Z_a - z_n), \quad (8)$$

where $(\mathbf{R}_a, Z_a)$ is the position vector of the a th vapor atom and z_n the perpendicular component of the position of the n th electron, and V_0 is the effective interaction strength which is related to the cross section A_{He} of a helium atom by $V_0^2 = \pi \hbar^4 A_{\text{He}} / m^2$.

The Wigner phonons in a magnetic field B are related to the phonons without magnetic fields by

$$\Omega_{\mathbf{k}\pm}^{(0)} = \frac{\sqrt{\omega_c^2 + (\omega_{\mathbf{k}l}^{(0)} + \omega_{\mathbf{k}t}^{(0)})^2} \pm \sqrt{\omega_c^2 + (\omega_{\mathbf{k}l}^{(0)} - \omega_{\mathbf{k}t}^{(0)})^2}}{2}, \quad (9)$$

where $\omega_{\mathbf{k}\lambda}^{(0)}$ ($\lambda = l, t$) are frequencies corresponding to the longitudinal (l) and the transverse (t) modes of the Wigner phonon without magnetic fields, and $\omega_c = eB/mc$ is the cyclotron frequency. When the scattering potentials are present, $\omega_{\mathbf{k}\lambda}^{(0)}$ will be modified to $\omega_{\mathbf{k}\lambda}$ by the scattering and they should be determined self-consistently. It follows that the spectra in such a case have a gap approximately given by⁵

$$\omega_{\mathbf{k}\lambda}^2 = \omega_{\mathbf{k}\lambda}^{(0)2} + v^2, \quad (10)$$

$$v^2 \approx \frac{1}{A} \sum_{\mathbf{q}} \frac{q^2 U_{\mathbf{q}}}{2mT} \exp\left(-\frac{q^2}{4m\omega_c}\right), \quad (11)$$

where T is the temperature in units of energy, and $U_{\mathbf{q}}$ the coupling function given by

$$U_{\mathbf{q}} = \frac{Te^2 F^2(q)}{\alpha q^2} + \frac{\hbar^3}{m\tau_v}. \quad (12)$$

The first term in Eq. (12) corresponds to the electron-ripplon scattering, and the second to the electron-vapor atom scattering where $\tau_v = 8mb/3\pi A_{\text{He}} n_v$ is the collision time due to helium vapor atoms with n_v being the vapor density. In accordance with this, $\Omega_{\mathbf{k}j}^{(0)}$ are modified to $\Omega_{\mathbf{k}j}$ in the same manner as in Eq. (9).

III. DYNAMIC STRUCTURE FACTOR

As usual, the dynamic structure factor (DSF) is defined through the density-density correlation function $S_{nm}(q, t) = \langle e^{i\mathbf{q} \cdot \mathbf{u}_n(t)} e^{-i\mathbf{q} \cdot \mathbf{u}_m(0)} \rangle$ by

$$S_{n-m}(q, \omega) = \int_{-\infty}^{\infty} e^{i\omega t} S_{nm}(q, t) dt, \quad (13)$$

where $\mathbf{u}_n$ is the displacement vector of the electron at the n th-site, and $\langle \dots \rangle$ denotes the thermal average.

This can be calculated readily by using the expression of the Fourier transform of the displacement vector $\mathbf{u}_n$ in the quantized representation⁵.

In a high magnetic field ($\hbar\omega_c \gg T$) the dominant DSF with $n = m$ can be expressed as a sum over contributions from all the Landau levels⁵:

$$S_0(q, \omega) = \frac{2\sqrt{\pi}\hbar}{\Gamma} \sum_{n=0}^{\infty} \frac{x^{n-\frac{1}{2}}}{n!} e^{\hbar(\omega - n\omega_c)/2T} \times \exp\left[-x \left(1 + \left(\frac{\Gamma}{4T}\right)^2\right) - \frac{\hbar^2(\omega - n\omega_c)^2}{x\Gamma^2}\right]. \quad (14)$$

Here, $x = \hbar q^2 / 2m\omega_c$, and the broadening parameter, Γ , is defined by

$$\Gamma^2 = \frac{2\hbar T}{\omega_c N} \sum_{\mathbf{k}, \lambda} \omega_{\mathbf{k}\lambda}^2 = \Gamma_e^2 + \Gamma_r^2 + \Gamma_v^2, \quad (15)$$

where Γ_e is related to the electron Coulomb interaction, Γ_r to the electron-ripplon, and Γ_v to electron-vapor atom scatterings, respectively, and are given by

$$\Gamma_e = \eta \omega_0 \sqrt{\frac{\hbar T}{\omega_c}}, \quad (16)$$

$$\Gamma_r = \sqrt{\frac{T}{\pi\alpha}} eF(q = \frac{\sqrt{2}}{l_c}), \quad (17)$$

$$\Gamma_v = \hbar \sqrt{\frac{2\omega_c}{\pi\tau_v}}, \quad (18)$$

where η is a numerical constant which may depend weakly on the plasma parameter⁷ and ≈ 1.21 at zero temperature, $l_c = (c\hbar/eB)^{1/2}$ the Landau magnetic length, and $\omega_0^2 = 4(\pi n_e)^{3/2} e^2 / m$ with n_e the surface density of electrons.

The present result Eq. (14) differs appreciably from the results by Monarkha *et al.*⁴ who determined the DSF phenomenologically, in which the factor $\exp[-x(\Gamma/4T)^2] \times \exp[\hbar(\omega - n\omega_c)/2T]$ is missing, and so the functional form with respect to x is different from ours. This difference has led to an overestimation of the contributions from the higher Landau levels in Ref. 4. Also, note that the broadening parameter Γ contains the contributions of the scattering effects and so, as will be shown in the next section, the linewidth goes over without divergence to the self-consistent Born approximation for independent electrons⁸, when the electron correlation effect becomes negligible. Therefore, this is regarded as an improvement over Dykman's result³ in which the linewidth diverges as n_e goes to zero.

Figure 1 illustrates an example of the DSF. As seen in Fig. 1, the DSF has local peaks at $(\omega/\omega_c \approx n + (n - 1/2)\Gamma^2/4T\hbar\omega_c, x \approx n - 1/2)$ for $n \neq 0$. The most important contributions to the DSF come from the terms with $n = 0$, and 1, and small enough q .

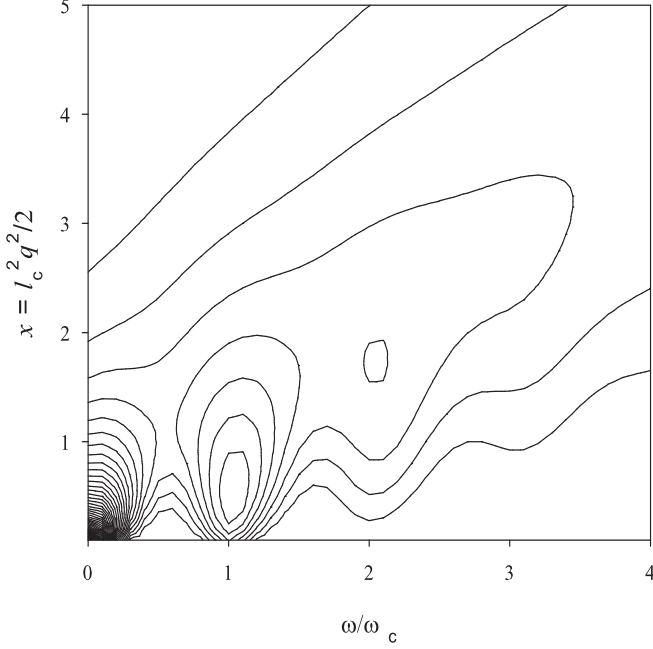


FIG. 1: Contour map of $S_0(q, \omega)$ at $B = 0.7$ T, $T = 0.72$ K and $n_e = 2 \cdot 10^8$ cm $^{-2}$.

IV. CYCLOTRON RESONANCE LINEWIDTH

The width function of the absorption line-shape is defined through the imaginary part of the memory function of the conductivity. Similar to the case of electrons in semiconductor heterostructures⁵, the width function of the present case takes the following form:

$$\gamma(\omega) = \frac{1 - e^{-\hbar\omega/T}}{\hbar\omega} \frac{1}{A} \sum_{\mathbf{q}} \frac{q^2 U_{\mathbf{q}}}{4m} S_0(q, \omega). \quad (19)$$

Inserting $S_0(q, \omega)$ in Eq. (14) into Eq. (19), we can obtain the final expression for the width function. At resonance ($\omega = \omega_c$), the CR linewidth is given by

$$\gamma(\omega_c) = \gamma_r(\omega_c) + \gamma_v(\omega_c). \quad (20)$$

In the above, the CR linewidth $\gamma_r(\omega_c)$ due to the ripplon scattering has the explicit form

$$\gamma_r(\omega_c) = \frac{T(eE_z)^2}{2\sqrt{\pi}\hbar\Gamma\alpha} \sinh \frac{\hbar\omega_c}{2T} \sum_{n=0}^{\infty} \frac{e^{-n\hbar\omega_c/2T}}{n!} G_n, \quad (21)$$

where G_n is defined by

$$G_n = \int_0^{\infty} x^{n-\frac{1}{2}} V^2(x) e^{-x(1+(\frac{\Gamma}{4T})^2) - \frac{\hbar^2\omega_c^2(1-n)^2}{x\Gamma^2}} dx, \quad (22)$$

$$V(x) = 1 + \frac{\hbar^2}{2ma_0 l_c^2 e E_z} x w \left(\frac{b}{l_c} \sqrt{\frac{x}{2}} \right). \quad (23)$$

The CR linewidth $\gamma_v(\omega_c)$ due to the vapor atom scattering is given by

$$\gamma_v(\omega_c) = \frac{2\hbar\omega_c}{\sqrt{\pi}\Gamma\tau_v} \sinh \frac{\hbar\omega_c}{2T} \sum_{n=0}^{\infty} \frac{e^{-n\hbar\omega_c/2T}}{n!} \times \left(\frac{\hbar\omega_c |1-n|}{\xi\Gamma} \right)^{n+\frac{3}{2}} K_{n+\frac{3}{2}} \left(\frac{2\xi\hbar\omega_c |1-n|}{\Gamma} \right), \quad (24)$$

where $\xi = \sqrt{1 + (\Gamma/4T)^2}$ and $K_{\nu}(z)$ is the modified Bessel function of the second kind.

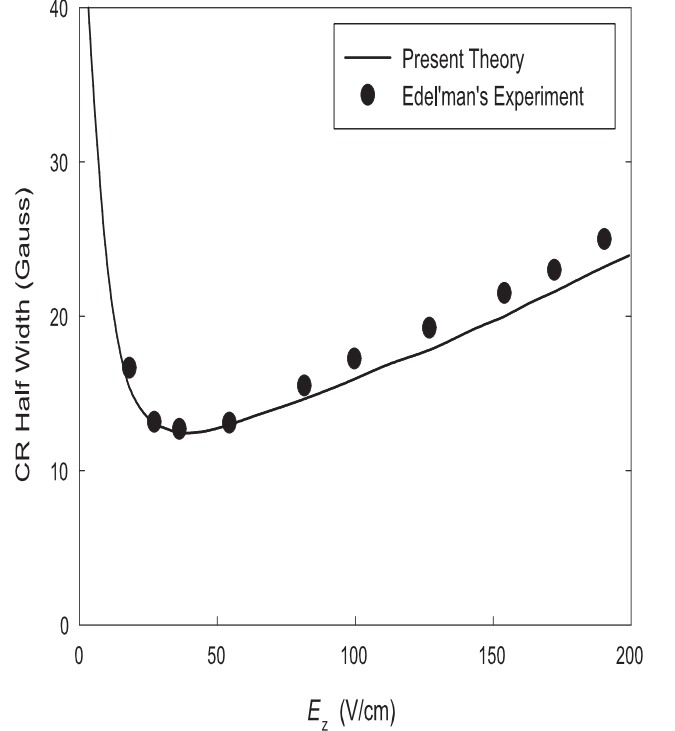


FIG. 2: The CR linewidth *vs.* holding electric fields E_z at $T = 0.72$ K. The holding electric field is taken to be the saturation value $E_z = 2\pi n_e$. Dots are taken from the experiments by Edel'man⁹.

Figure 2 illustrates the applied electric field dependence of the CR linewidth in the condition that the electron density is saturated: $E_z = 2\pi n_e$. The solid curve represents the results of the present theory, and the dots the experimental results by Edel'man⁹. A comment is in order here. The existence of the Wigner crystal phase is marginal in Edel'man's experiment. However, our theory does work beyond the Wigner crystal phase and is applicable even in such a case, since the electron correlation effect taken into account through Γ_e has the same form as in Ref.^{3,7} though with a different physical interpretation. At this temperature both of ripplon and vapor scatterings are equally important. As shown in Fig. 2, the CR linewidth first decreases with increasing E_z in the small

electric field range ($E_z < 30$ V/cm), and then increases for the larger holding fields. It is emphasized here that the term with $n = 1$ in the CR linewidth in Eq. (21) and Eq. (24) monotonically decreases with the electron density, and therefore the dip of the CR linewidth cannot be reproduced without the terms with $n = 0$ and $n \geq 2$. Our numerical results of the CR linewidth agree quantitatively with the experiment and better than the previous theories. Note that we have not introduced any fitting parameters.

V. CONCLUSION

We have presented a theoretical analysis of the cyclotron resonance of the Wigner crystal on the surface of

liquid helium under quantizing magnetic fields, not phenomenologically as was done in previous theories, but by taking the electron correlation and the electron scatterings on the same footing. We studied the DSF and the CR linewidth by fully considering all the contributions from the higher Landau levels. The numerical calculations show that the contributions from higher Landau levels are important to reproduce the non-monotonic dependence in E_z of the CR linewidth properly. The electron density dependence of the CR linewidth is shown to be in the quantitative agreement with experimental results by Edel'man⁹ without any fitting parameters.

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